

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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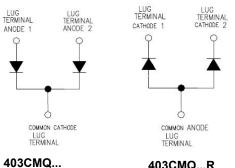
# 403CMQ080/R 403CMQ100/R SCHOTTKY RECTIFIER



#### **Features**

- 175℃ T<sub>J</sub> operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



403CMQ...R

### **Applications**

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- **Reverse battery protection**
- Converters
- **UPS System**
- Welding

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	80	403CMQ080/R	V
DC Blocking Voltage	V RWM VR		100	403CMQ100/R	V
Average Rectified Forward Current		50% duty cycle @T <sub>C</sub> =85°C,	200(Per Leg)		A
		rectangular wave form	400(Per Device)		
Peak One Cycle Non-Repetitive	I <sub>FSM</sub>	8.3 ms, half Sine pulse	3960		Α
Surge Current (Per Leg)	+				
Non-Repetitive Avalanche Energy(Peg Leg)	E <sub>AS</sub>	T <sub>J</sub> =25°C,I <sub>AS</sub> =1A,L=30mH 15		15	mJ
Repetitive Avalanche Current		Current decaying linearly to zero			
(Peg Leg)	I <sub>AR</sub>	in 1 µsec Frequency limited by		1	Α
		$T_J$ max. $V_A$ =1.5 $\times$ $V_R$ typical			

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com
     sales@ smc-diodes.com









# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 200A, Pulse, T <sub>J</sub> = 25 °C @ 400A, Pulse, T <sub>J</sub> = 25 °C	0.77 0.85	0.83 0.97	V
	V <sub>F2</sub>	@ 200A, Pulse, T <sub>J</sub> = 125 °C @ 400A, Pulse, T <sub>J</sub> = 125 °C	0.61 0.70	0.69 0.82	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25  ^{\circ}\text{C}$	0.2	6	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R_1} T_J = 125  ^{\circ}\text{C}$	2	140	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	4800	5500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specific	Units	
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.10		°C/W
Mounting Torque	Тм	-	Mounting Torque	24(min) 35(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79 g		
Case Style	PRM4 Isolated				

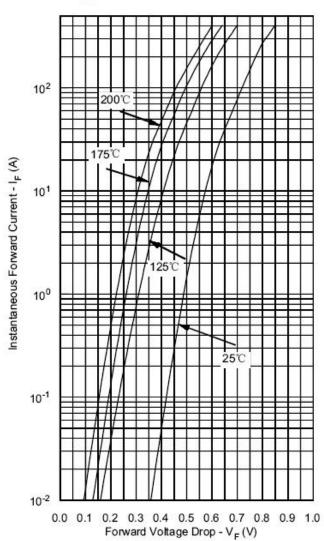




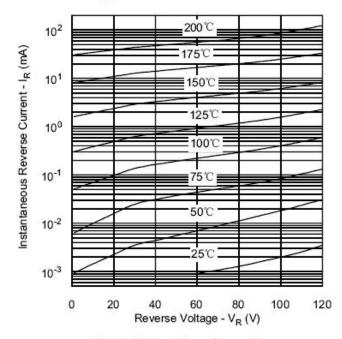


# **Ratings and Characteristics Curves**

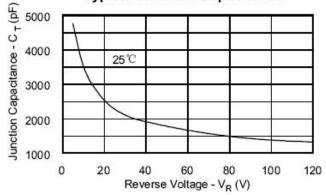
### **Typical Forward Characteristics**



#### Typical Reverse Characteristics



### **Typical Junction Capacitance**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

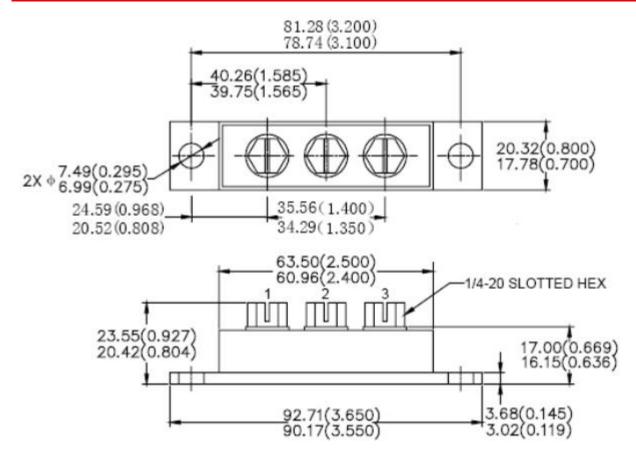
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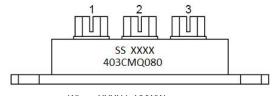


## **Mechanical Dimensions PRM4 Isolated(Millimeters/Inches)**



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2 Suffix R Denotes for Reversed Polarity.

### **Marking Diagram**



Where XXXX is YYWW

403CMQ080 = Part name SS = SS YY = Year WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping
403CMQ SERIES	PRM4 Isolated (Pb-Free)	9 pcs/box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com
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